NSN 5962-01-052-3835

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 1.240 inches and 1.280 inches

Body Width:

Between 0.520 inches and 0.580 inches

Body Height:

Between 0.060 inches and 0.210 inches

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

High speed and high current and 3-state output and programmed and monolithic

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

13 input

Current Rating Per Characteristic:

5.00 milliamperes reverse current, dc microamperes

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

4.00 input picofarads and 8.00 output picofarads

Time Rating Per Chacteristic:

55.00 nanoseconds access

Memory Device Type:

Prom

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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